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FAN5362

3MHz, 500mA / 750mA Synchronous Buck Regulator

Features

- 3MHz Fixed-Frequency Operation
- 45µA Typical Quiescent Current
- 1.80 to 3.6V Fixed Output Voltage
- 500mA or 750mA Output Current Capability
- 2.7V to 5.5V Input Voltage Range
- Smooth Transitions to/from 100% Duty Cycle when V_{IN} Drops
- PFM Mode for High Efficiency in Light Load
- Best-in-Class Load Transient Response
- Best-in-Class Efficiency
- Forced PWM and External Clock Synchronization
- Internal Soft-Start
- Input Under-Voltage Lockout (UVLO)
- Thermal Shutdown and Overload Protection
- 6-Bump WLCSP, 0.4mm Pitch or 6-Lead 2 x 2mm Ultrathin Molded Leadless Package

Applications

- SD Flash Memory Power Supply
- RF Transceiver Power
- Cell Phones, Smart Phones
- Tablets, Netbooks®, Ultra-Mobile PCs
- 3G, LTE, WiMAX™, WiBro®, and WiFi® Data Cards
- Gaming Devices, Digital Cameras DC/DC Micro Modules

Description

The FAN5362 is a 500mA or 750mA, step-down, switching voltage regulator that delivers a fixed output voltage from an input voltage supply of 2.7V to 5.5V. Using a proprietary architecture with synchronous rectification, the FAN5362 is capable of delivering a peak efficiency of 96%, while maintaining efficiency over 90% with load currents as low as 1mA.

This regulator transitions seamlessly into and out of 100% duty cycle operation when the supply dips to or below the regulation setpoint and smoothly recovers full regulation without overshoot when the supply recovers.

The regulator operates at a nominal fixed frequency of 3MHz, which reduces the value of the external components to 1µH for the output inductor and 4.7µF for the output capacitor. The PWM modulator can be synchronized to an external frequency source.

At moderate and light loads, pulse frequency modulation is used to operate the device in power-save mode with a typical quiescent current of 45µA. Even with such a low quiescent current, the part exhibits excellent transient response during large load swings. At higher loads, the system automatically switches to fixed-frequency control, operating at 3MHz. In shutdown mode, the supply current drops below 1µA, reducing power consumption. For applications that require minimum ripple or fixed frequency, PFM mode can be disabled using the MODE pin.

The FAN5362 is available in 6-bump, 0.4mm pitch, Wafer-Level Chip-Scale Package (WLCSP) and 6-Lead 2 x 2mm Ultrathin Molded Leadless Package (UMLP).

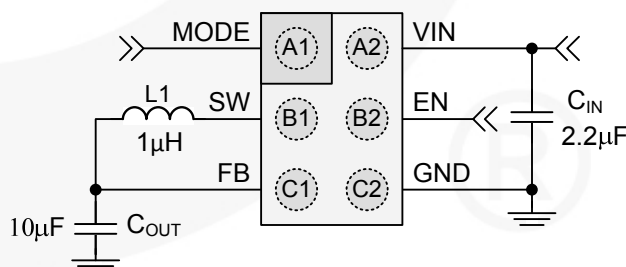


Figure 1. Typical Application

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Ordering Information

Part Number	Output Voltage ⁽¹⁾	Output Current (mA)	Operating Temperature Range	Package	Packing Method
FAN5362UC21X ⁽²⁾	2.1	750	-40 to 85°C	WLCSP-6, 0.4mm Pitch	Tape and Reel
FAN5362UC25X ⁽²⁾	2.5	500			
FAN5362UC27X	2.7	500			
FAN5362UC29X	2.9	500			
FAN5362UC33X	3.3	500			
FAN5362UMP29X	2.9	500		6-Lead, 2 x 2mm UMLP	
FAN5362UMP33X	3.3	500			

Note:

- Other voltage options available on request. Contact a Fairchild representative.
- Preliminary; not full production release at this time. Contact a Fairchild representative for information.

Table 1. Recommended Components for Circuit in Figure 1

Component	Description	Example Part	Typical
L1	1μH, 2012, 190mΩ, 800mA	Murata LQM21PN1R0MC0	1μH
C _{IN}	2.2μF, 6.3V, X5R, 0402	Murata GRM155R60J225ME15	2.2μF
	2.2μF, 6.3V, X5R, 0603	GRM188R60J225KE19D	
C _{OUT}	4.7μF, X5R, 0603	Murata GRM188R60J475M	4.7μF
	10μF, X5R, 0603	Murata GRM188R60J106ME47D	10.0μF

Pin Configuration

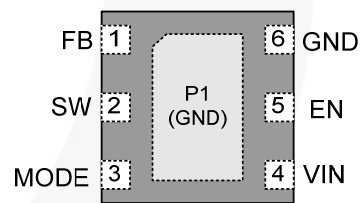
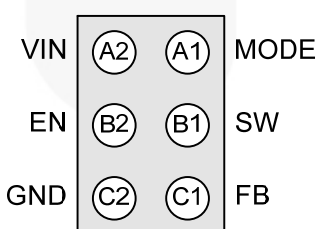
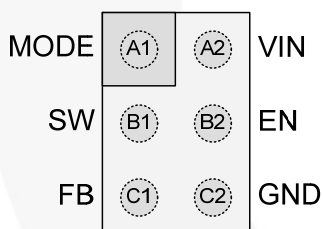


Figure 2. WLCSP, Bumps Facing Down **Figure 3. WLCSP, Bumps Facing Up** **Figure 4. UMLP, Leads Facing Down**

Pin Definitions

WLCSP Bump #	UMLP Pin #	Name	Description
A1	3	MODE	Logic 1 on this pin forces the IC to stay in PWM mode. Logic 0 allows the IC to automatically switch to PFM during light loads. The regulator also synchronizes its switching frequency to two times the frequency provided on this pin. Do not leave this pin floating. When tying HIGH, use at least 1kΩ series resistor if V _{IN} is expected to exceed 4.5V.
B1	2	SW	Switching Node. Connect to output inductor.
C1	1	FB	Feedback / V_{OUT}. Connect to output voltage.
C2	6	GND	Ground. Power and IC ground. All signals are referenced to this pin.
B2	5	EN	Enable. The device is in shutdown mode when voltage to this pin is <0.4V and enabled when >1.2V. Do not leave this pin floating. When tying HIGH, use at least 1kΩ series resistor if V _{IN} is expected to exceed 4.5V.
A2	4	VIN	Input Voltage. Connect to input power source.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter		Min.	Max.	Unit
V _{IN}	Input Voltage		−0.3	6.5	V
V _{SW}	Voltage on SW Pin		−0.3	V _{IN} + 0.3 ⁽³⁾	V
V _{CTRL}	EN and MODE Pin Voltage		−0.3	V _{IN} + 0.3 ⁽³⁾	V
V _{FB}	FB Pin		−0.3	4	V
ESD	Electrostatic Discharge Protection Level	Human Body Model per JESD22-A114	3.0		kV
		Charged Device Model per JESD22-C101	1.5		
T _J	Junction Temperature		−40	+150	°C
T _{STG}	Storage Temperature		−65	+150	°C
T _L	Lead Soldering Temperature, 10 Seconds			+260	°C

Note:

3. Lesser of 6.5V or $V_{IN} + 0.3V$.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{CC}	Supply Voltage Range	2.7 ⁽⁴⁾		5.5	V
I_{OUT}	Output Current for 2.1V	0		750	mA
	Output Current for 2.5V, 2.7V, 2.9V, 3.3V	0		500	
L	Inductor		1		μH
C_{IN}	Input Capacitor		2.2		μF
C_{OUT}	Output Capacitor		10	24	μF
T_A	Operating Ambient Temperature	-40		+85	°C
T_J	Operating Junction Temperature	-40		+125	°C

Note:

4. Minimum $V_{IN} = V_{OUT} + 200mV$ or 2.7V, whichever is greater.

Thermal Properties

Junction-to-ambient thermal resistance is a function of application and board layout. This data is measured with four-layer 1s2p boards in accordance to JEDEC standard JESD51. Special attention must be paid not to exceed junction temperature $T_{J(max)}$ at a given ambient temperature T_A .

Symbol	Parameter		Typical	Unit
θ_{JA}	Junction-to-Ambient Thermal Resistance		150	°C/W
			49	

Electrical Characteristics

Minimum and maximum values are at $V_{IN} = V_{EN} = 2.7V$ to $5.5V$, $V_{MODE} = 0V$ (AUTO Mode), $T_A = -40^{\circ}C$ to $+85^{\circ}C$; circuit of Figure 1, unless otherwise noted. Typical values are at $T_A = 25^{\circ}C$, $V_{IN} = V_{EN} = 3.6V$, $V_{MODE} = 0V$, $C_{OUT} = 10\mu F$.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit	
Power Supplies							
I _Q	Quiescent Current	No Load, Not Switching, V _{IN} > 3V		45	75	μA	
		PWM Mode		5		mA	
I _(SD)	Shutdown Supply Current	EN = GND		0.05	1.00	μA	
V _{UVLO}	Under-Voltage Lockout Threshold	Rising V _{IN}		2.5	2.6	V	
V _{UVHYST}	Under-Voltage Lockout Hysteresis			175		mV	
V _(ENH)	Enable HIGH-Level Input Voltage		1.05			V	
V _(ENL)	Enable LOW-Level Input Voltage				0.4	V	
I _(EN)	Enable Input Leakage Current	EN to V _{IN} or GND		0.01	1.00	μA	
V _(MH)	MODE HIGH-Level Input Voltage		1.05			V	
V _(ML)	MODE LOW-Level Input Voltage				0.4	V	
I _(M)	MODE Input Leakage Current	MODE to V _{IN} or GND		0.01	1.00	μA	
Switching and Synchronization							
f _{SW}	Switching Frequency ⁽⁵⁾	V _{IN} = 3.6V, T _A = 25°C	2.7	3.0	3.3	MHz	
f _{SYNC}	MODE Synchronization Range ⁽⁵⁾	Square Wave at MODE Input	1.3	1.5	1.7	MHz	
Regulation							
V _O	Output Voltage Accuracy	2.10V	I _{LOAD} = 0 to 750mA	2.037 (-3%)	2.100	2.163 (+3%)	V
		2.50V	I _{LOAD} = 0 to 400mA, V _{IN} ≥ V _{OUT} + 200mV	2.375 (-5%)	2.500	2.575 (+3%)	
			I _{LOAD} = 0 to 500mA, V _{IN} ≥ V _{OUT} + 300mV	2.425 (-3%)	2.500	2.575 (+3%)	
		2.70V, 2.90V, 3.30V	I _{LOAD} = 0 to 400mA, V _{IN} ≥ V _{OUT} + 150mV	-5%		+3%	
			I _{LOAD} = 0 to 500mA, V _{IN} ≥ V _{OUT} + 300mV	-3%		+3%	
t _{SS}	Soft-Start	From EN Rising Edge		180	300	μs	
Output Driver							
R _{DS(on)}	PMOS On Resistance	V _{IN} = V _{GS} = 3.6V		330		mΩ	
	NMOS On Resistance	V _{IN} = V _{GS} = 3.6V		300		mΩ	
I _{LIM(OL)}	PMOS Peak Current Limit ⁽⁵⁾	V _{OUT} = 2.1V		1375		mA	
		V _{OUT} = 2.5V, 2.7V, 2.9V, 3.3V	800	1000	1150	mA	
T _{TSD}	Thermal Shutdown			150		°C	
T _{HYS}	Thermal Shutdown Hysteresis			15		°C	

Notes:

- Limited by the effect of t_{OFF} minimum (see Figure 8 in Typical Performance Characteristics).
- The Electrical Characteristics table reflects open-loop data. Refer to the Operation Description and Typical Characteristics for closed-loop data.

Typical Characteristics

Unless otherwise noted, $V_{IN}=V_{EN}=3.6V$, $V_{MODE}=0$ (AUTO), $V_{OUT}=2.9V$, $C_{OUT}=10\mu F$, and $T_A=25^\circ C$.

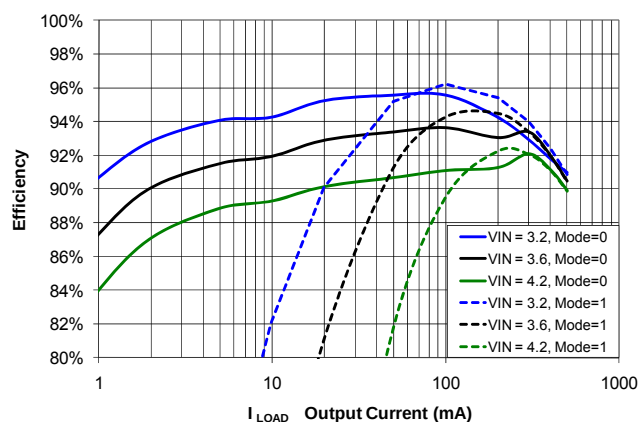


Figure 5. Efficiency vs. Load Current and Input Supply

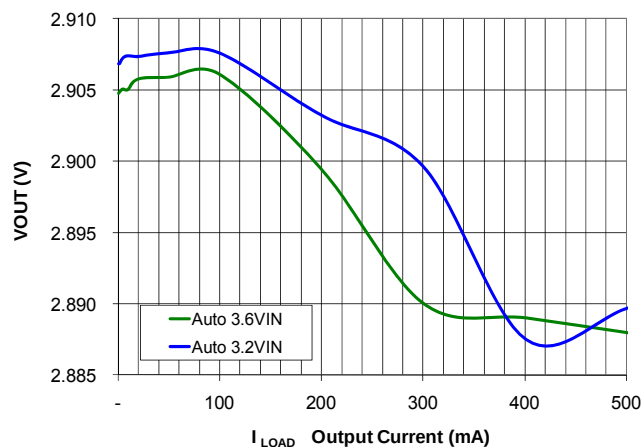


Figure 6. Load Regulation

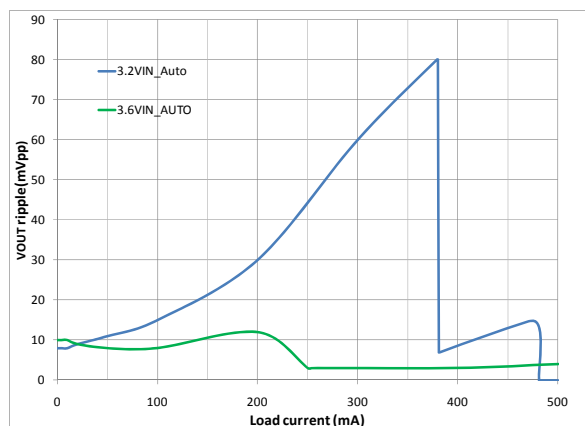


Figure 7. Ripple

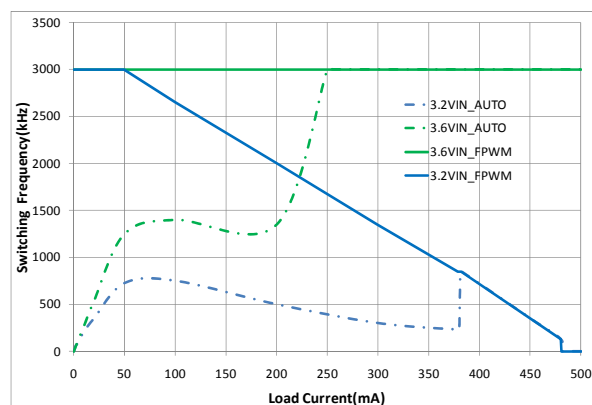


Figure 8. Effect of $t_{OFF(MIN)}$ on Reducing Switching Frequency

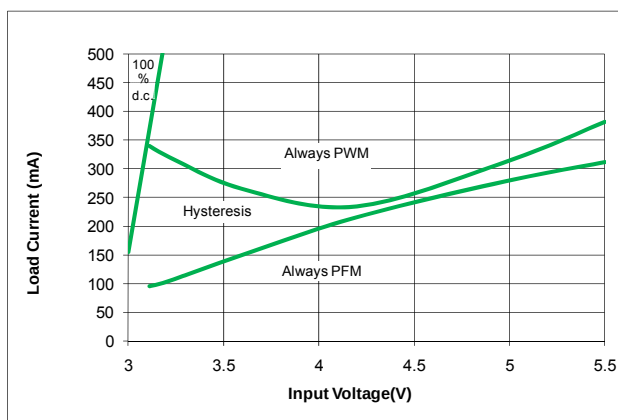


Figure 9. PFM / PWM Boundaries

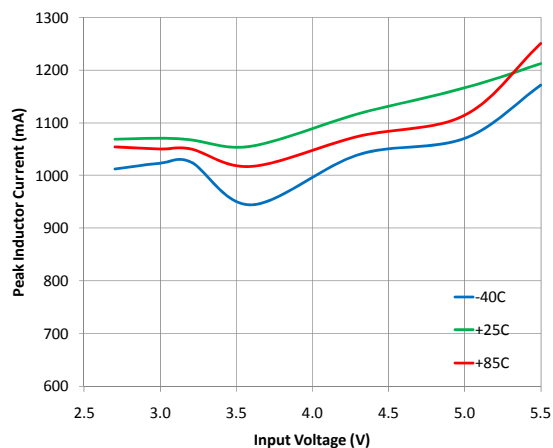


Figure 10. Peak Inductor Current

Typical Characteristics

Unless otherwise noted, $V_{IN}=V_{EN}=3.6V$, $V_{MODE}=0$ (AUTO), $V_{OUT}=2.9V$, $C_{OUT}=10\mu F$, and $T_A=25^\circ C$.

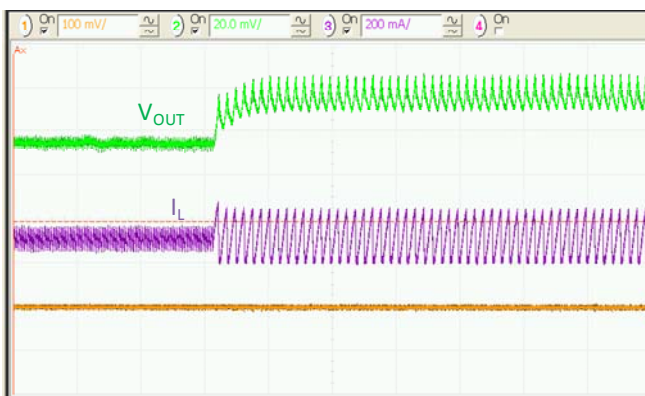
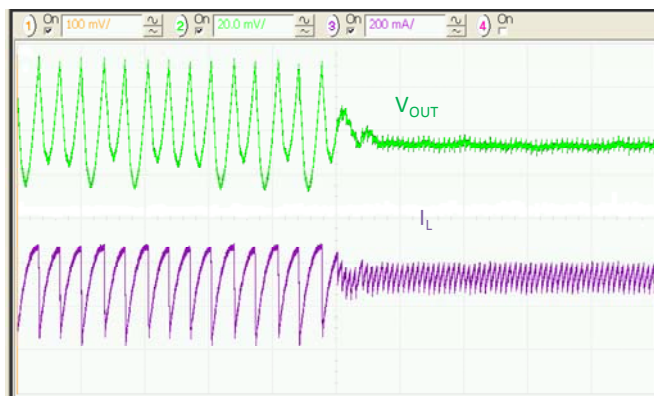


Figure 11. PFM to PWM Transition at $V_{IN}=3.2V$, $10\mu s/div$. Figure 12. PWM to PFM Transition at $V_{IN}=3.2V$, $10\mu s/div$.

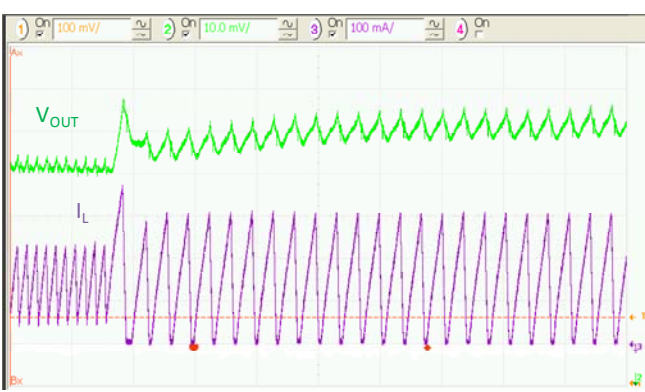


Figure 13. PFM to PWM Transition at $V_{IN}=3.6V$, $2\mu s/div$. Figure 14. PWM to PFM Transition at $V_{IN}=3.6V$, $2\mu s/div$.

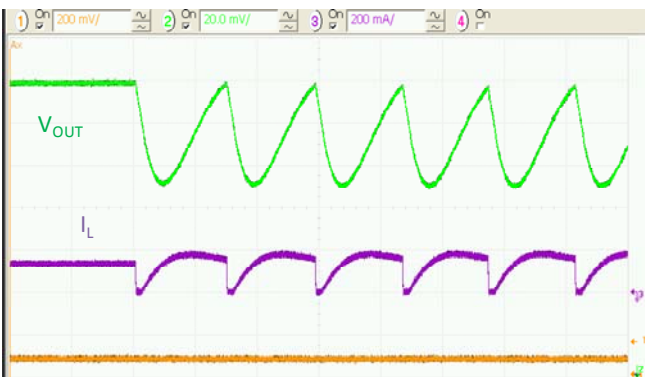
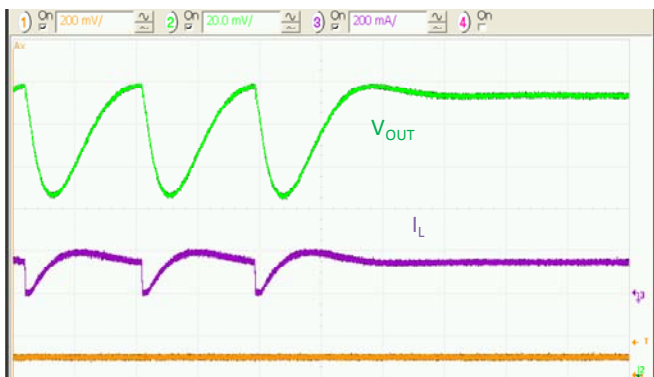


Figure 15. Regular Switching to 100% Duty Cycle Transition at $V_{IN}=3.2V$, $5\mu s/div$.

Figure 16. 100% Duty Cycle to Regular Switching Transition at $V_{IN}=3.2V$, $5\mu s/div$.

Typical Characteristics

Unless otherwise noted, $V_{IN}=V_{EN}=3.6V$, $V_{MODE}=0$ (AUTO), $V_{OUT}=2.9V$, $C_{OUT}=10\mu F$, and $T_A=25^\circ C$.



Figure 17. Startup Ramping $V_{IN}=V_{EN}$ with 500mA Load, 1ms/div.



Figure 18. Startup and Shutdown through V_{EN} with 500mA Load, 50μs/div.

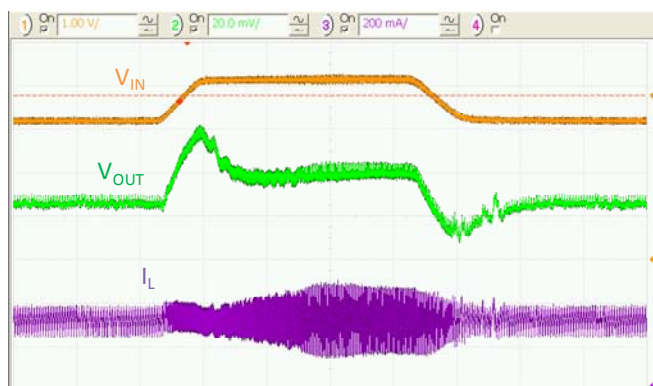


Figure 19. Line Transient at $V_{IN}=3.2V$ to $4.2V$, 300mA Load, $t_{RISE}=t_{FALL}=10\mu s$, 20μs/div.

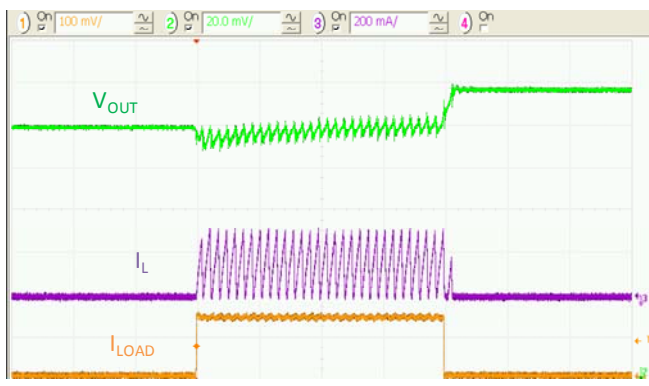


Figure 20. Load Transient 0mA to 150mA, $V_{IN}=3.6V$, $t_{RISE}=t_{FALL}=100ns$, 5μs/div.

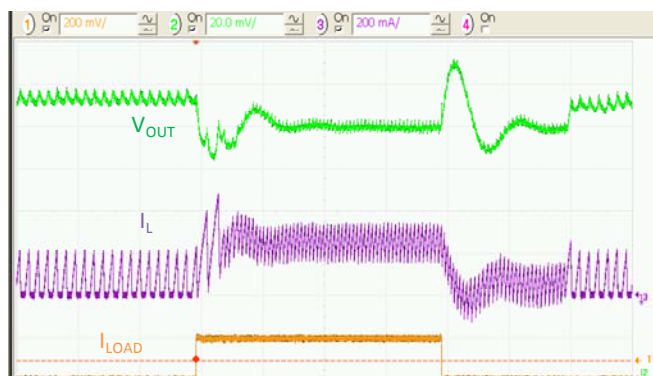


Figure 21. Load Transient 50mA to 250mA, $V_{IN}=3.6V$, $t_{RISE}=t_{FALL}=100ns$, 5μs/div.



Figure 22. Load Transient 150mA to 400mA, $V_{IN}=3.6V$, $t_{RISE}=t_{FALL}=100ns$, 5μs/div.

Typical Characteristics

Unless otherwise noted, $V_{IN}=V_{EN}=3.6V$, $V_{MODE}=0$ (AUTO), $V_{OUT}=2.9V$, $C_{OUT}=10\mu F$, and $T_A=25^\circ C$.



Figure 23. Load Transient 50mA to 250mA, $V_{IN}=3V$, $t_{RISE}=t_{FALL}=100ns$, 5µs/div.



Figure 24. Load Transient 150mA to 400mA, $V_{IN}=3V$, $t_{RISE}=t_{FALL}=100ns$, 5µs/div.

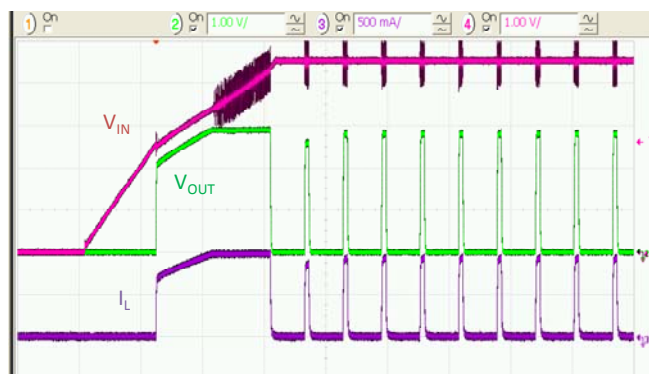


Figure 25. Startup Ramping $V_{IN}=V_{EN}$, into Overload, Load=3Ω, 5ms/div.

Operation Description

FAN5362 is a 500mA or 750mA, step-down switching voltage regulator that delivers a fixed output voltage from an input voltage supply up to 5.5V. Using a proprietary architecture with synchronous rectification, FAN5362 is capable of delivering a peak efficiency above 96%, while maintaining efficiency above 90% at load currents as low as 1mA. The regulator operates at a nominal frequency of 3MHz at full load, which reduces the value of the external components to 1μH for the inductor and 4.7μF for the output capacitor. High efficiency is maintained at light load with single-pulse PFM mode.

Control Scheme

The FAN5362 uses a proprietary, non-linear, fixed-frequency PWM modulator to deliver a fast load transient response, while maintaining a constant switching frequency over a wide range of operating conditions. The regulator performance is independent of the output capacitor ESR, allowing for the use of ceramic output capacitors. Although this type of operation normally results in a switching frequency that varies with input voltage and load current, an internal frequency loop holds the switching frequency constant over a large range of input voltages and load currents.

For very light loads, the FAN5362 operates in discontinuous current (DCM) single-pulse PFM mode, which produces low output ripple compared with other PFM architectures. Transition between PWM and PFM is seamless, with a glitch of less than 18mV at V_{OUT} during the transition between DCM and CCM modes.

Combined with exceptional transient response characteristics, the very low quiescent current of the controller (45μA) maintains high efficiency, even at very light loads, while preserving fast transient response for applications requiring tight output regulation.

100% Duty Cycle Operation

When V_{IN} approaches V_{OUT} , the regulator increases its duty cycle until 100% duty cycle is reached. As the duty cycle approaches 100%, the switching frequency declines due to the minimum off-time ($t_{OFF(MIN)}$) of about 35ns imposed by the control circuit. When 100% duty cycle is reached, V_{OUT} follows V_{IN} with a drop-out voltage ($V_{DROPOUT}$) determined by the total resistance between V_{IN} and V_{OUT} :

$$V_{DROPOUT} = I_{LOAD} \cdot (PMOS R_{DS(ON)} + DCR_L) \quad (1)$$

To calculate the worst-case $V_{DROPOUT}$, use the maximum PMOS $R_{DS(ON)}$ at high temperature from Figure 6.

Enable and Soft Start

When the EN pin is LOW, the IC is shut down and the part draws very little current. In addition, during shutdown, FB is actively discharged to ground through a 230Ω path. Raising EN above its threshold voltage activates the part and starts the soft-start cycle. During soft-start, the internal reference is ramped using an exponential RC shape to prevent any overshoot of the output voltage. Current limiting minimizes inrush during soft-start.

Synchronous rectification is inhibited during soft-start, allowing the IC to start into a pre-charged load.

The IC may fail to start if heavy load is applied during startup and/or if excessive C_{OUT} is used. This is due to the current-limit fault response, which protects the IC in the event of an over-current condition present during soft-start.

The current required to charge C_{OUT} during soft-start is commonly referred to as “displacement current” and given as:

$$I_{DISP} = C_{OUT} \cdot \frac{dV}{dt} \quad (2)$$

where $\frac{dV}{dt}$ refers to the soft-start slew rate.

To prevent shutdown during soft-start, the following condition must be met:

$$I_{DISP} + I_{LOAD} < I_{MAX(DC)} \quad (3)$$

where $I_{MAX(DC)}$ is the maximum load current the IC is guaranteed to support (500mA or 750mA).

MODE Pin

Logic 1 on this pin forces the IC to stay in PWM mode. A logic 0 allows the IC to automatically switch to PFM during light loads. If the MODE pin is toggled, the converter synchronizes its switching frequency to four times the frequency on the mode pin (f_{MODE}).

At startup, the mode pin must be held LOW or HIGH for at least 10μs to ensure that the converter does not attempt to synchronize to this pin.

Under-Voltage Lockout

When EN is HIGH, the under-voltage lockout keeps the part from operating until the input supply voltage rises high enough to properly operate. This ensures no misbehavior of the regulator during startup or shutdown.

Current Limiting

A heavy load or short circuit on the output causes the current in the inductor to increase until a maximum current threshold is reached in the high-side switch. Upon reaching this point, the high-side switch turns off, preventing high currents from causing damage. 16 consecutive PWM cycles in current limit causes the regulator to shut down and stay off for about 2900μs before attempting a restart.

In the event of a short circuit, the soft-start circuit attempts to restart at 240μs, which results in a duty cycle of less than 10%, providing current into a short.

The closed-loop peak-current limit, $I_{LIM(PK)}$, is not the same as the open-loop tested current limit, $I_{LIM(OL)}$, in the Electrical Characteristics table. This is primarily due to the effect of propagation delays of the IC current limit comparator.

Thermal Shutdown

When the die temperature increases, due to a high load condition and/or a high ambient temperature, the output switching is disabled until the temperature on the die has fallen sufficiently. The junction temperature at which the thermal shutdown activates is nominally 150°C with a 20°C hysteresis.

Minimum Off-Time Effect on Switching Frequency

$t_{OFF(MIN)}$ is 35ns. This imposes constraints on the maximum $\frac{V_{OUT}}{V_{IN}}$ that the FAN5362 can provide, or the maximum output voltage it can provide at low V_{OUT} while maintaining a fixed switching frequency in PWM mode.

When V_{IN} is high, fixed switching is maintained as long as $\frac{V_{OUT}}{V_{IN}} \leq 1 - t_{OFF(MIN)} \cdot f_{SW} \approx 0.7$.

The switching frequency drops when the regulator cannot provide sufficient duty cycle at 3MHz to maintain regulation. This occurs when V_{IN} is below 3.3V at nominal load currents.

The calculation for switching frequency is given by:

$$f_{SW} = \min\left(\frac{1}{t_{SW(MAX)}}, 3\text{MHz}\right) \quad (4)$$

where:

$$t_{SW(MAX)} = 35\text{ns} \cdot \left(1 + \frac{V_{OUT} + I_{OUT} \cdot R_{OFF}}{V_{IN} - I_{OUT} \cdot R_{ON} - V_{OUT}}\right) \quad (5)$$

where:

$$R_{OFF} = R_{DS(ON_N)} + DCR_L$$

$$R_{ON} = R_{DS(ON_P)} + DCR_L$$

Applications Information

Selecting the Inductor

The output inductor must meet both the required inductance and the energy handling capability of the application.

The inductor value affects the average current limit, the PWM-to-PFM transition point, the output voltage ripple, and the efficiency.

The ripple current (ΔI) of the regulator is:

$$\Delta I \approx \frac{V_{OUT}}{V_{IN}} \cdot \left(\frac{V_{IN} - V_{OUT}}{L \cdot f_{SW}}\right) \quad (6)$$

The maximum average load current, $I_{MAX(LOAD)}$ is related to the peak current limit, $I_{LIM(PK)}$ by the ripple current:

$$I_{MAX(LOAD)} = I_{LIM(PK)} - \frac{\Delta I}{2} \quad (7)$$

The FAN5362 is optimized for operation with $L=1\mu\text{H}$, but is stable with inductances up to $1.5\mu\text{H}$ (nominal) and down to 470nH . The inductor should be rated to maintain at least 80% of its value at $I_{LIM(PK)}$. Failure to do so lowers the amount of DC current that the IC can deliver.

Efficiency is affected by the inductor DCR and inductance value. Decreasing the inductor value for a given physical size typically decreases the DCR; but since ΔI increases, the RMS current increases, as do the core and skin effect losses.

$$I_{RMS} = \sqrt{I_{OUT(DC)}^2 + \frac{\Delta I^2}{12}} \quad (8)$$

The increased RMS current produces higher losses through the $R_{DS(ON)}$ of the IC MOSFETs as well as the inductor ESR.

Increasing the inductor value produces lower RMS currents, but degrades transient response. For a given physical inductor size, increased inductance usually results in an inductor with lower saturation current and higher DCR.

Inductor Current Rating

The FAN5362's current limit circuit can allow a peak current of 1.25A to flow through L1 under worst-case conditions. If it is possible for the load to draw that much continuous current, the inductor should be capable of sustaining that current or failing in a safe manner.

Output Capacitor

While 4.7μF capacitors are available in 0402 package size, 0603 capacitors are recommended due to the severe DC voltage bias degradation in capacitance value that the 0402 exhibits.

Increasing C_{OUT} has no effect on loop stability and can therefore be increased to reduce output voltage ripple or to improve transient response. Output voltage ripple, ΔV_{OUT} , is:

$$\Delta V_{OUT} = \Delta I \cdot \left(\frac{1}{8 \cdot C_{OUT} \cdot f_{SW}} + ESR\right) \quad (9)$$

If values greater than 24μF of C_{OUT} are used, the regulator may fail to start. See the sections on Enable and Soft Start for more information.

Input Capacitor

The 2.2μF ceramic input capacitor should be placed as close as possible to the VIN pin and GND to minimize the parasitic inductance. If a long wire is used to bring power to the IC, additional "bulk" capacitance (electrolytic or tantalum) should be placed between C_{IN} and the power source lead to reduce ringing that can occur between the inductance of the power source leads and C_{IN} .

PCB Layout Guidelines

There are only three external components: the inductor, input capacitor, and the output capacitor. For any buck switcher IC, including the FAN5362, it is important to place a low-ESR input capacitor very close to the IC, as shown in Figure 26. The input capacitor ensures good input decoupling, which helps reduce noise appearing at the output terminals and ensures that the control sections of the IC do not behave erratically due to excessive noise. This reduces switching cycle jitter and ensures good overall performance. It is important to place the common GND of C_{IN} and C_{OUT} as close as possible to the C2 terminal. There is some flexibility in moving the inductor further away from the IC; in that case, V_{OUT} should be considered at the C_{OUT} terminal.

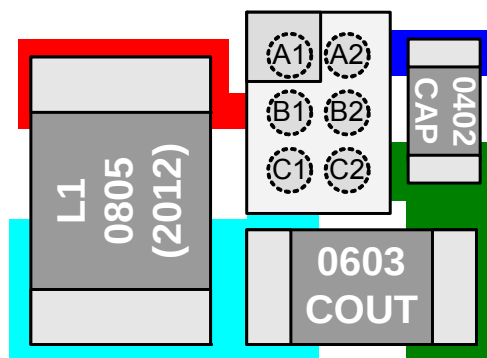


Figure 26. PCB Layout Recommendation

Physical Dimensions

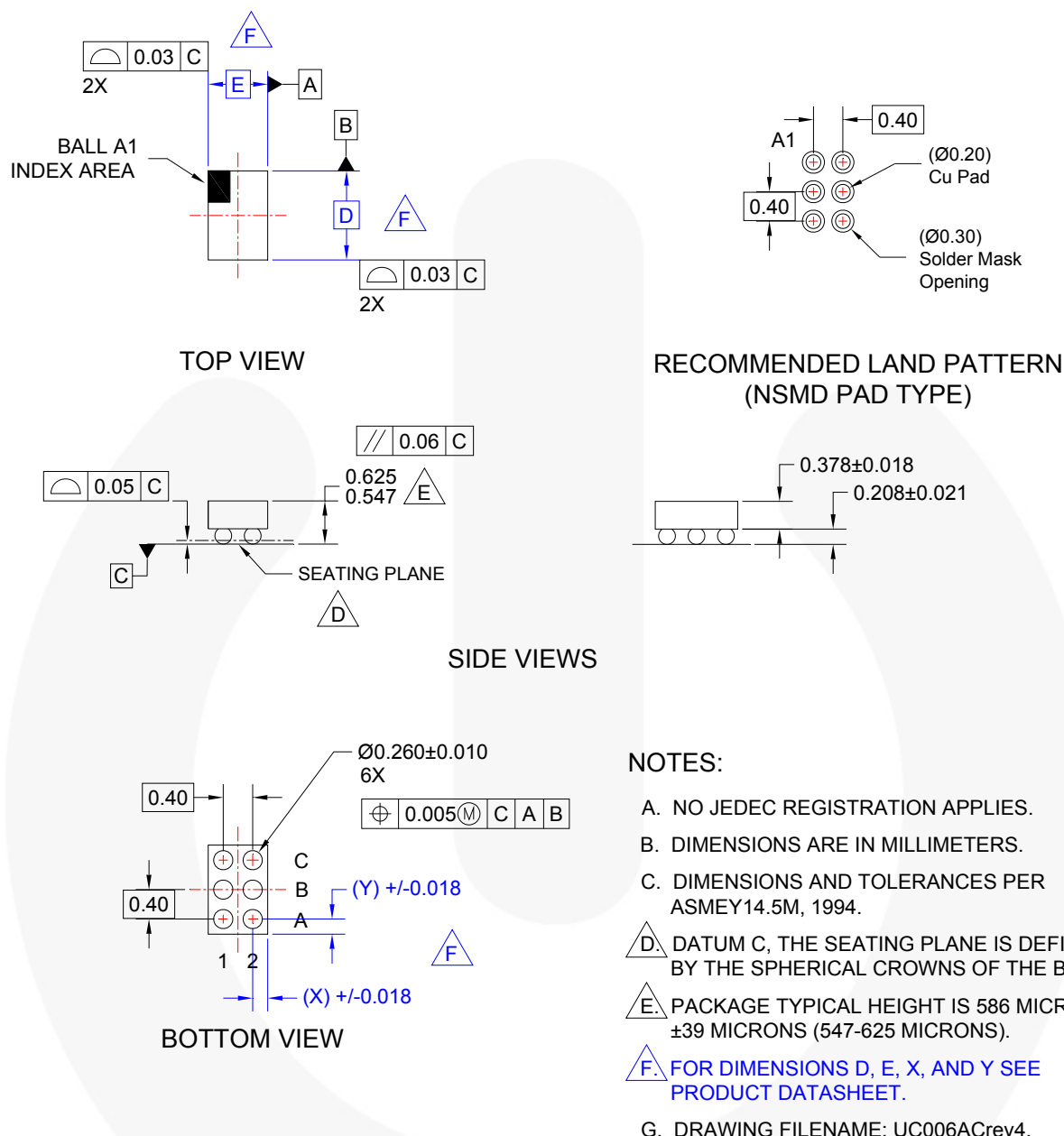


Figure 27. 6-Ball, Wafer-Level Chip-Scale Package (WLCSP), 2x3 Array, 0.4mm Pitch, 250µm Ball

Product-Specific Dimensions

Product	D	E	X	Y
FAN5362UCX	1.310 +/-0.030	0.960 +/-0.030	0.280	0.255

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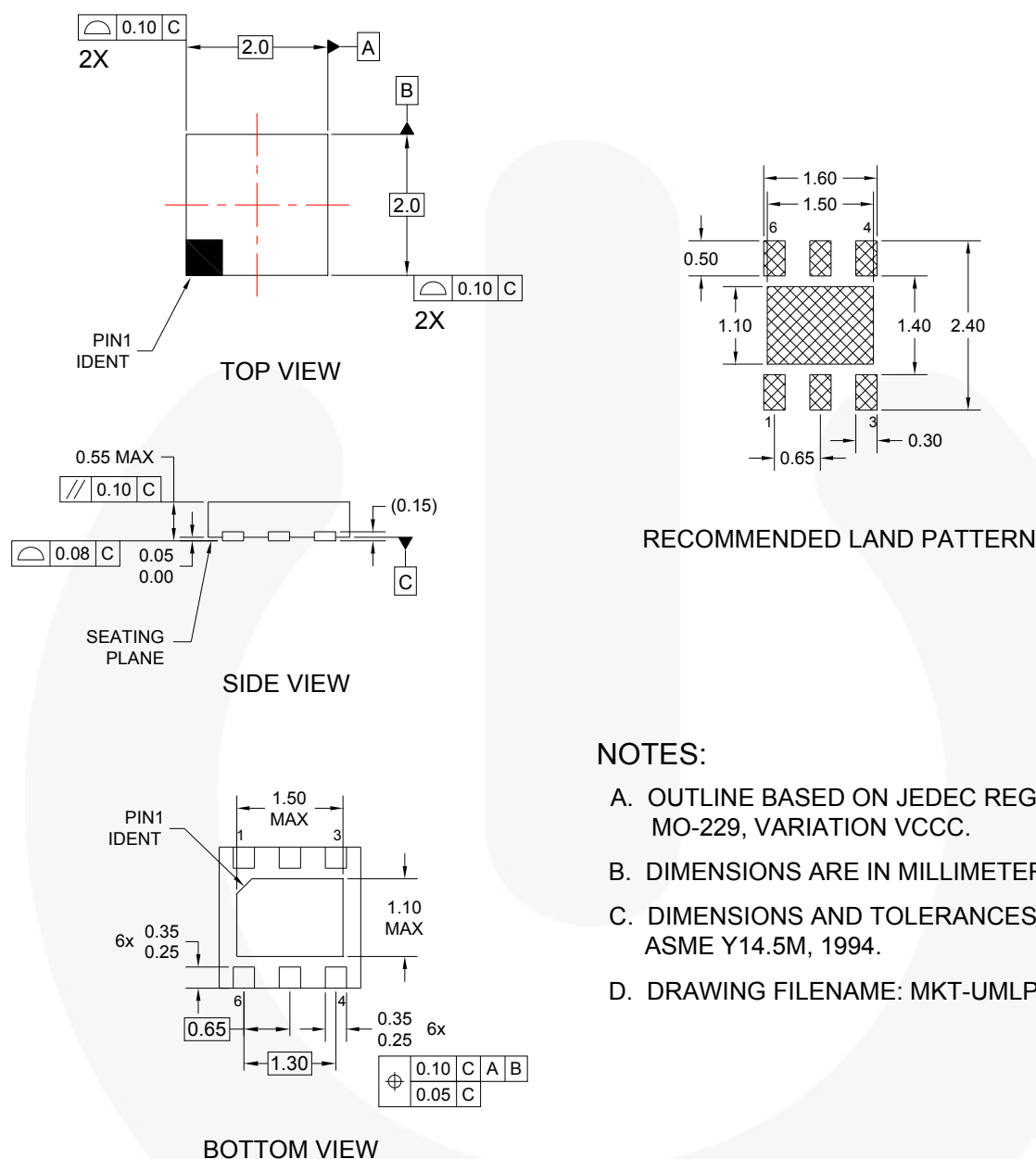


Figure 28. 6-Lead, 2 x 2mm, Ultra-Thin Molded Leadless Package (UMLP)

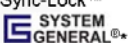
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